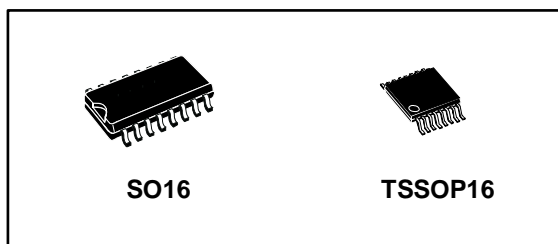


## 8-channel multiplexer

Datasheet - production data



### Features

- High speed:  $t_{PD} = 17 \text{ ns}$  (typ.) at  $V_{CC} = 6 \text{ V}$
- Low power dissipation:  
 $I_{CC} = 4 \mu\text{A}$  (max.) at  $T_A = 25 \text{ }^\circ\text{C}$
- High noise immunity:  
 $V_{NIH} = V_{NIL} = 28 \% V_{CC}$  (min.)
- Symmetrical output impedance:  
 $|I_{OH}| = I_{OL} = 4 \text{ mA}$  (min)
- Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- Wide operating voltage range:  
 $V_{CC}$  (OPR) = 2 V to 6 V
- Pin and function compatible with 74 series 151
- ESD performance
  - CDM: 1 kV
  - HBM: 2 kV
  - MM: 200 V

### Description

The M74HC151 is a high-speed CMOS 8-channel multiplexer manufactured using silicon gate C<sup>2</sup>MOS technology.

It provides, in one device, the ability to select one bit of data from up to eight sources. The M74HC151 can be used as a universal function generator to generate any logic function of four variables. Outputs Y and W are complementary; the selection depends on the address inputs A, B, and C. The strobe input must be taken low to enable this device. When the strobe is high, the W output is forced high and consequently the Y output goes low. All inputs are equipped with protection circuits to guard against static discharge and transient excess voltage.

**Table 1: Device summary**

Order code	Temperature range	Package	Packaging	Marking
M74HC151YRM13TR <sup>(1)</sup>	-40 °C to +125 °C	SO16 (automotive grade) <sup>1</sup>	Tape and reel	74HC151Y
M74HC151RM13TR	-55 °C to +125 °C	SO16	Tape and reel	74HC151
M74HC151TTR	-55 °C to +125 °C	TSSOP16	Tape and reel	HC151
M74HC151YTTR <sup>1</sup>	-40 °C to +125 °C	TSSOP16 (automotive grade) <sup>1</sup>	Tape and reel	HC151Y

#### Notes:

<sup>(1)</sup>Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

---

**Contents**

<b>1</b>	<b>Pin information .....</b>	<b>5</b>
<b>2</b>	<b>Functional description .....</b>	<b>6</b>
<b>3</b>	<b>Electrical characteristics .....</b>	<b>8</b>
<b>4</b>	<b>Package information .....</b>	<b>13</b>
	4.1    SO16 package information.....	13
	4.2    TSSOP16 package information.....	15
<b>5</b>	<b>Revision history .....</b>	<b>16</b>

---

## List of tables

Table 1: Device summary .....	1
Table 2: Pin description .....	5
Table 3: Truth table .....	6
Table 4: Absolute maximum ratings .....	8
Table 5: Recommended operating conditions .....	8
Table 6: DC specifications .....	9
Table 7: AC electrical characteristics ( $C_L = 50$ pF, input $t_r = t_f = 6$ ns) .....	10
Table 8: Capacitive characteristics .....	11
Table 9: Plastic SO16 package mechanical data .....	14
Table 10: TSSOP16 package mechanical data .....	15
Table 11: Document revision history .....	16

---

## List of figures

Figure 1: Pin connections and IEC logic symbols .....	5
Figure 2: Input and output equivalent circuit.....	6
Figure 3: Logic diagram .....	7
Figure 4: Test circuit .....	11
Figure 5: Waveform 1: propagation delay times (f = 1 MHz; 50% duty cycle) .....	12
Figure 6: Waveform 2: propagation delay times (f = 1 MHz; 50% duty cycle) .....	12
Figure 7: Plastic SO16 package mechanical outline .....	13
Figure 8: TSSOP16 package mechanical outline .....	15

# 1 Pin information

Figure 1: Pin connections and IEC logic symbols

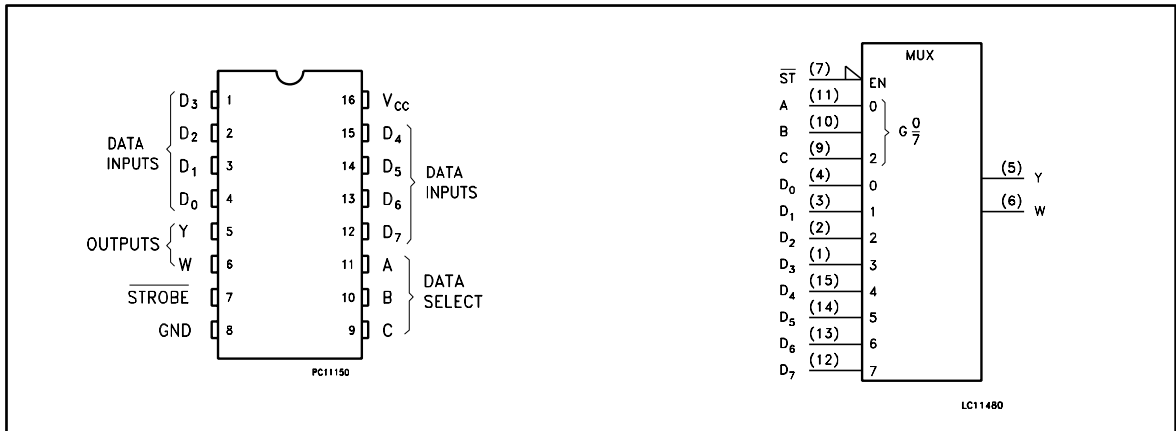


Table 2: Pin description

Pin number	Symbol	Name and function
4, 3, 2, 1, 15, 14, 13, 12	D <sub>0</sub> to D <sub>7</sub>	Multiplexer inputs
5	Y	Multiplexer output
6	W	Complementary multiplexer output
7	$\overline{\text{STROBE}}$	Strobe input
11, 10, 9	A, B, C	Select inputs
8	GND	Ground (0 V)
16	V <sub>CC</sub>	Positive supply voltage

## 2 Functional description

Table 3: Truth table

Inputs				Outputs	
Select			$\overline{\text{STROBE}}$	Y	W
C	B	A	S		
X <sup>(1)</sup>	X <sup>1</sup>	X <sup>1</sup>	H	L	H
L	L	L	L	D <sub>0</sub>	$\overline{D}_0$
L	L	H	L	D <sub>1</sub>	$\overline{D}_1$
L	H	L	L	D <sub>2</sub>	$\overline{D}_2$
L	H	H	L	D <sub>3</sub>	$\overline{D}_3$
H	L	L	L	D <sub>4</sub>	$\overline{D}_4$
H	L	H	L	D <sub>5</sub>	$\overline{D}_5$
H	H	L	L	D <sub>6</sub>	$\overline{D}_6$
H	H	H	L	D <sub>7</sub>	$\overline{D}_7$

**Notes:**

<sup>(1)</sup>X: don't care

Figure 2: Input and output equivalent circuit

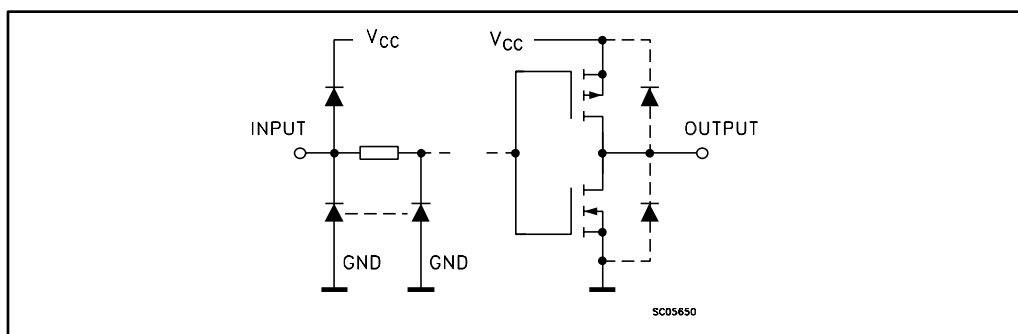
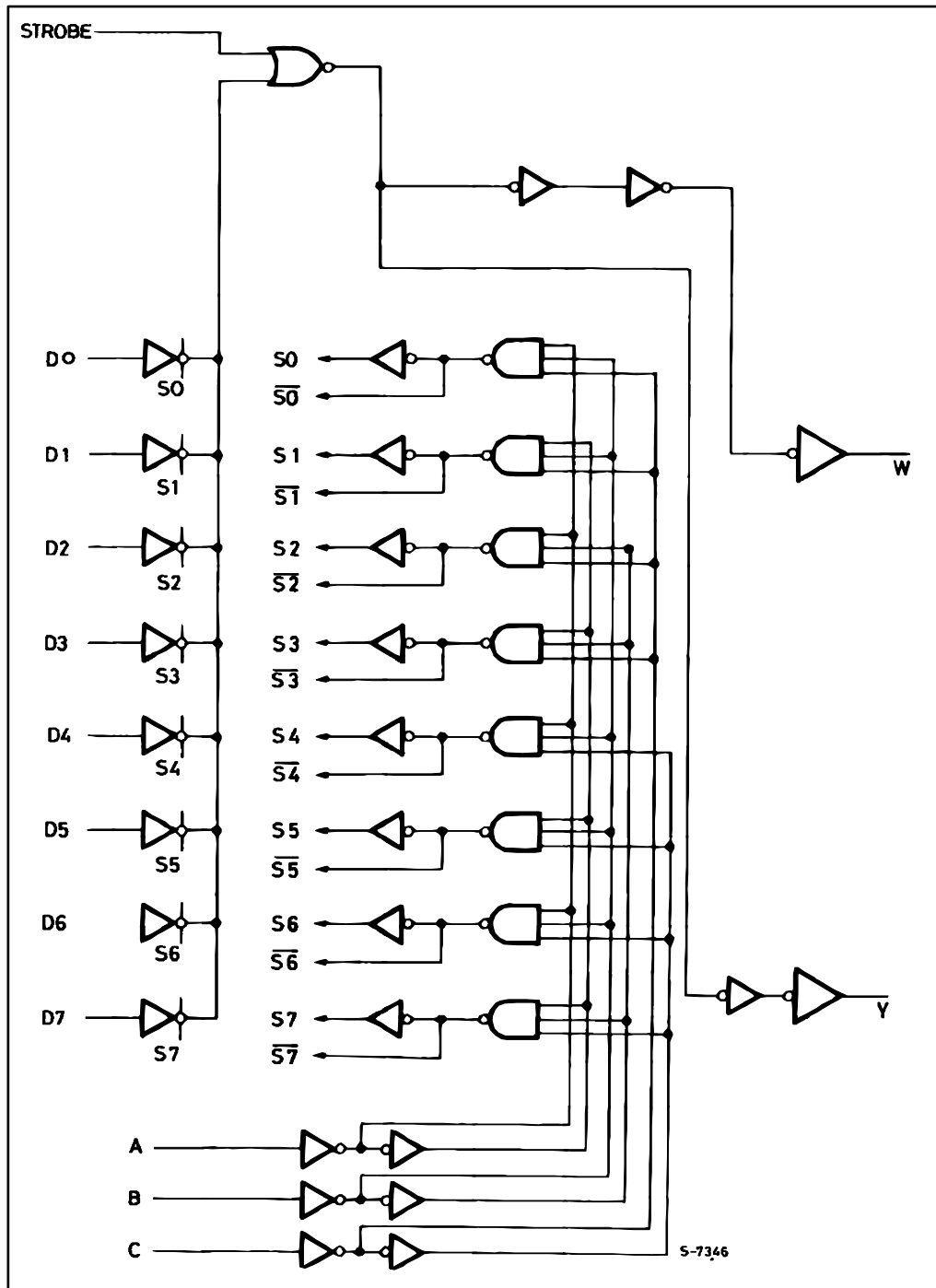


Figure 3: Logic diagram



This logic diagram has not been used to estimate propagation delays.

### 3 Electrical characteristics

Stressing the device above the ratings listed in the "Absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only, and operation of the device at these or any other conditions above those indicated in the operating sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Table 4: Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage	-0.5 to +7	V
$V_I$	DC input voltage	-0.5 to $V_{CC}$ to +0.5	V
$V_O$	DC output voltage	-0.5 to $V_{CC}$ to +0.5	V
$I_{IK}$	DC input diode current	$\pm 20$	mA
$I_{OK}$	DC output diode current	$\pm 20$	mA
$I_O$	DC output current	$\pm 25$	mA
$I_{CC}$ or $I_{GND}$	DC $V_{CC}$ or ground current	$\pm 50$	mA
$P_D$	Power dissipation	500 <sup>(1)</sup>	mW
$T_{stg}$	Storage temperature	-65 to +150	°C
$T_L$	Lead temperature (10 sec.)	300	°C

**Notes:**

<sup>(1)</sup>500 mW at 65 °C; derate to 300 mW by 10 mW/°C from 65 °C to 85 °C

**Table 5: Recommended operating conditions**

Symbol	Parameter	Value	Unit	
$V_{CC}$	Supply voltage	2 to 6	V	
$V_I$	Input voltage	0 to $V_{CC}$	V	
$V_O$	Output voltage	0 to $V_{CC}$	V	
$T_{op}$	Operating temperature	-55 to 125	°C	
$t_r, t_f$	Input rise and fall time	$V_{CC} = 2.0$ V	0 to 1000	ns
		$V_{CC} = 4.5$ V	0 to 500	ns
		$V_{CC} = 6.0$ V	0 to 400	ns



Table 6: DC specifications

Symbol	Parameter	Test condition		Value						Unit	
		V <sub>CC</sub> (V)		T <sub>A</sub> = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
V <sub>IH</sub>	High-level input voltage	2.0		1.5			1.5		1.5		V
		4.5		3.15			3.15		3.15		
		6.0		4.2			4.2		4.2		
V <sub>IL</sub>	Low-level input voltage	2.0				0.5		0.5		0.5	V
		4.5				1.35		1.35		1.35	
		6.0				1.8		1.8		1.8	
V <sub>OH</sub>	High-level output voltage	2.0	I <sub>O</sub> = -20 μA	1.9	2.0		1.9		1.9		V
		4.5	I <sub>O</sub> = -20 μA	4.4	4.5		4.4		4.4		
		6.0	I <sub>O</sub> = -20 μA	5.9	6.0		5.9		5.9		
		4.5	I <sub>O</sub> = -4.0 mA	4.18	4.31		4.13		4.10		
		6.0	I <sub>O</sub> = -5.2 mA	5.68	5.8		5.63		5.60		
V <sub>OL</sub>	Low-level output voltage	2.0	I <sub>O</sub> = 20 μA		0.0	0.1		0.1		0.1	V
		4.5	I <sub>O</sub> = 20 μA		0.0	0.1		0.1		0.1	
		6.0	I <sub>O</sub> = 20 μA		0.0	0.1		0.1		0.1	
		4.5	I <sub>O</sub> = 4.0 mA		0.17	0.26		0.33		0.40	
		6.0	I <sub>O</sub> = 5.2 mA		0.18	0.26		0.33		0.40	
I <sub>I</sub>	Input leakage current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND			±0.1		±1		±1	μA
I <sub>CC</sub>	Quiescent supply current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND			4		40		80	μA

Table 7: AC electrical characteristics ( $C_L = 50$  pF, input  $t_r = t_f = 6$  ns)

Symbol	Parameter	Test condition	Value						Unit	
			$T_A = 25^\circ\text{C}$			$-40$ to $85^\circ\text{C}$		$-55$ to $125^\circ\text{C}$		
			$V_{CC}$ (V)	Min.	Typ.	Max.	Min.	Max.		Min.
$t_{TLH}$ $t_{THL}$	Output transition time	2.0		30	75		95		110	ns
		4.5		8	15		19		22	
		6.0		7	13		16		19	
$t_{PLH}$ $t_{PHL}$	Propagation delay time (D – W)	2.0		56	130		165		190	ns
		4.5		16	26		33		38	
		6.0		14	22		28		32	
$t_{PLH}$ $t_{PHL}$	Propagation delay time (D – Y)	2.0		56	130		165		190	ns
		4.5		16	26		33		38	
		6.0		14	22		28		32	
$t_{PLH}$ $t_{PHL}$	Propagation delay time ( $\overline{\text{STROBE}}$ – W)	2.0		30	85		105		125	ns
		4.5		10	17		21		25	
		6.0		9	14		18		21	
$t_{PLH}$ $t_{PHL}$	Propagation delay time ( $\overline{\text{STROBE}}$ – Y)	2.0		30	85		105		125	ns
		4.5		10	17		21		25	
		6.0		9	14		18		21	
$t_{PLH}$ $t_{PHL}$	Propagation delay time (A, B, C – W)	2.0		72	160		200		235	ns
		4.5		20	32		40		47	
		6.0		17	27		34		40	
$t_{PLH}$ $t_{PHL}$	Propagation delay time (A, B, C – Y)	2.0		72	160		200		235	ns
		4.5		20	32		40		47	
		6.0		17	27		34		40	

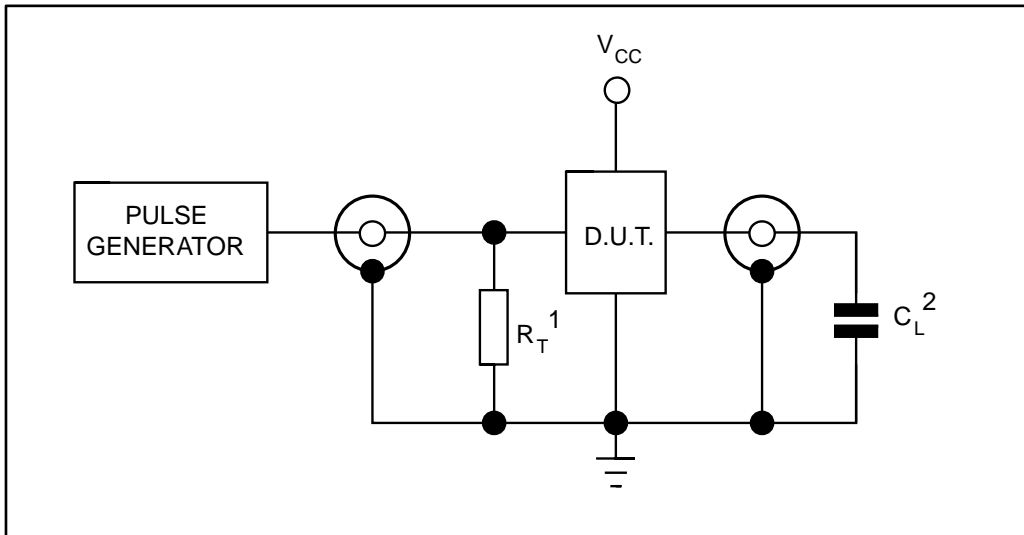
Table 8: Capacitive characteristics

Symbol	Parameter	Test condition	Value						Unit	
			T <sub>A</sub> = 25°C			-40 to 85°C		-55 to 125°C		
			V <sub>CC</sub> (V)	Min.	Typ.	Max.	Min.	Max.		Min.
C <sub>IN</sub>	Input capacitance	5.0		5	10		10		10	pF
C <sub>PD</sub>	Power dissipation capacitance <sup>(1)</sup>	5.0		63						pF

**Notes:**

<sup>(1)</sup>C<sub>PD</sub> is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load (refer to the test circuit). The average operating current can be obtained by the following equation: I<sub>CC(opr)</sub> = C<sub>PD</sub> × V<sub>CC</sub> × f<sub>IN</sub> + I<sub>CC</sub>

Figure 4: Test circuit



1. R<sub>T</sub> = Z<sub>OUT</sub> of pulse generator (typically 50 ohm)
2. C<sub>L</sub> = 50 pF or equivalent (includes jig and probe capacitance)

Figure 5: Waveform 1: propagation delay times (f = 1 MHz; 50% duty cycle)

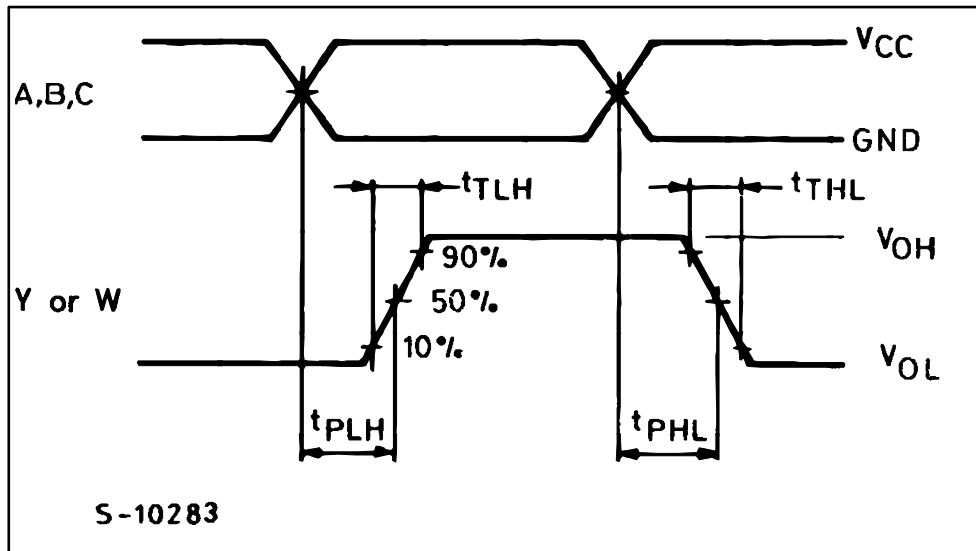
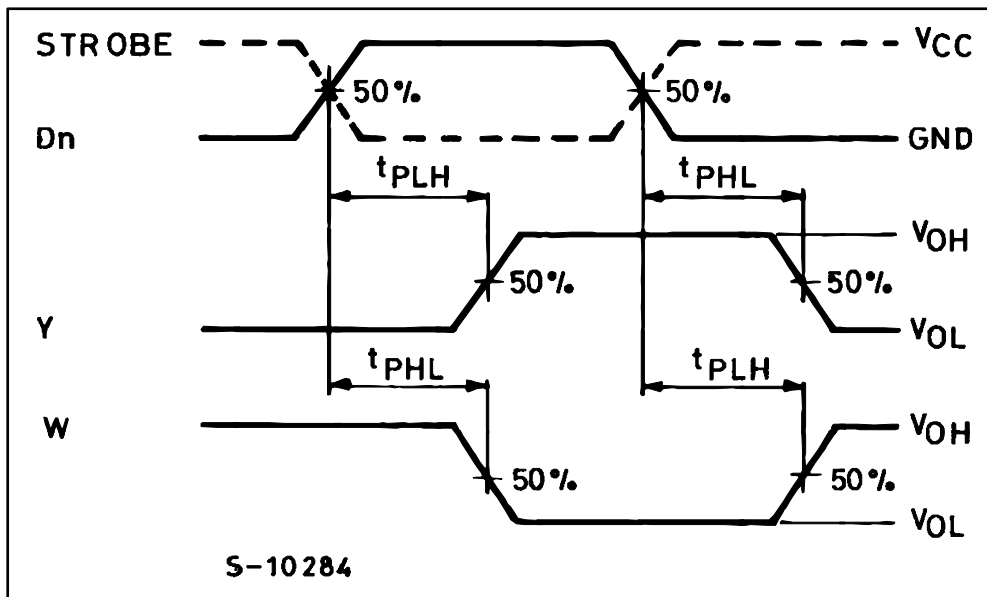


Figure 6: Waveform 2: propagation delay times (f = 1 MHz; 50% duty cycle)



## 4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 4.1 SO16 package information

Figure 7: Plastic SO16 package mechanical outline

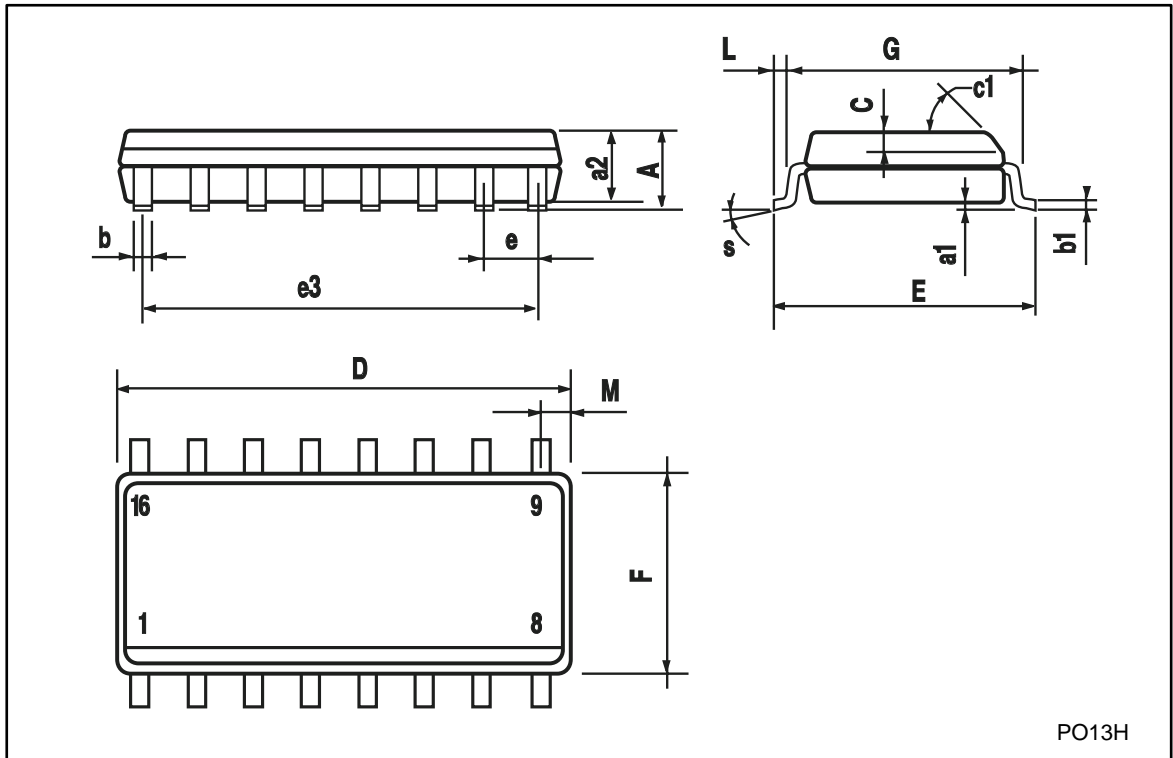
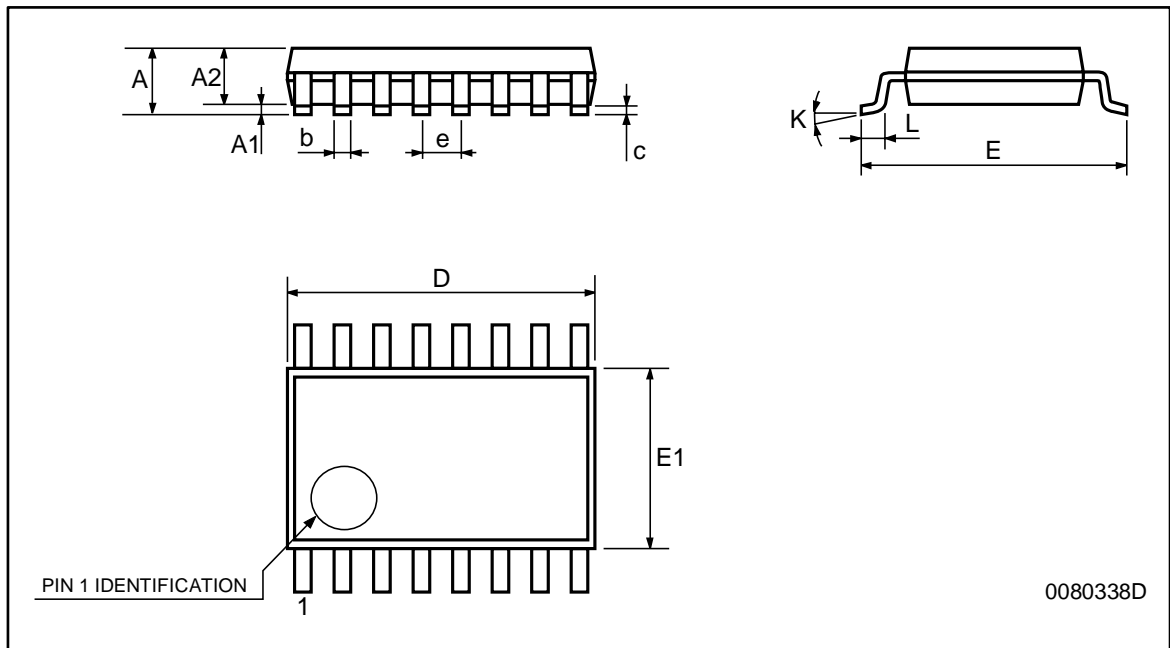


Table 9: Plastic SO16 package mechanical data

Dimensions	mm.			inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45 ° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8 ° (max.)					

## 4.2 TSSOP16 package information

Figure 8: TSSOP16 package mechanical outline



0080338D

Table 10: TSSOP16 package mechanical data

Dimensions	mm.			inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030

## 5 Revision history

Table 11: Document revision history

Date	Version	Change
Jul-2001	1	Initial release
01-Nov-2013	2	Added ESD performance to <a href="#">Section "Features"</a> Added automotive grade order codes, temperature ranges and marking information to <a href="#">Table 1: "Device summary"</a> Removed DIP16 package option Revised document presentation, minor textual updates



**Please Read Carefully**

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

**UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.**

**ST PRODUCTS ARE NOT DESIGNED OR AUTHORIZED FOR USE IN: (A) SAFETY CRITICAL APPLICATIONS SUCH AS LIFE SUPPORTING, ACTIVE IMPLANTED DEVICES OR SYSTEMS WITH PRODUCT FUNCTIONAL SAFETY REQUIREMENTS; (B) AERONAUTIC APPLICATIONS; (C) AUTOMOTIVE APPLICATIONS OR ENVIRONMENTS, AND/OR (D) AEROSPACE APPLICATIONS OR ENVIRONMENTS. WHERE ST PRODUCTS ARE NOT DESIGNED FOR SUCH USE, THE PURCHASER SHALL USE PRODUCTS AT PURCHASER'S SOLE RISK, EVEN IF ST HAS BEEN INFORMED IN WRITING OF SUCH USAGE, UNLESS A PRODUCT IS EXPRESSLY DESIGNATED BY ST AS BEING INTENDED FOR "AUTOMOTIVE, AUTOMOTIVE SAFETY OR MEDICAL" INDUSTRY DOMAINS ACCORDING TO ST PRODUCT DESIGN SPECIFICATIONS. PRODUCTS FORMALLY ESCC, QML OR JAN QUALIFIED ARE DEEMED SUITABLE FOR USE IN AEROSPACE BY THE CORRESPONDING GOVERNMENTAL AGENCY.**

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2013 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy  
- Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United  
States of America

[www.st.com](http://www.st.com)